

Gold Bonded

1N276

Germanium Diodes

Optimized for Radio Frequency Response

Can be used in many AM, FM and TV-IF applications, replacing point contact devices.

Applications

- AM/FM detectors
- Ratio detectors
- FM discriminators
- TV audio detectors
- RF input probes
- TV video detectors

Features

- Lower leakage current
- Flat junction capacitance
- High mechanical strength
- At least 1 million hours MTBF
- BKC's Sigma-Bond™ plating for problem free solderability

Absolute Maximum Ratings at $T_{amb} = 25^{\circ}\text{C}$ Unless Otherwise Specified

Parameter	Symbols	Min.	Max.	Units
Peak Inverse Voltage	PIV	**	70	Volts
Surge Current, t = 1 Second	I _S	0.4	Amps	
Peak Operating Current	I _{FSR}	270	mA	
Operating and Storage Temperatures	T _{J & STG}	-60	+90	°C

Electrical Characteristics at $T_{amb} = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbols	Min.	Typ.	Max.	Units
Forward Voltage Drop	I _F = 40 mA	V _F	**	1.0	Volts	
Breakdown Voltage	I _R = 1.0 mA	PIV	**	75	Volts	
Reverse Leakage	V _R = 10 Volts	I _R	**	5.0	µA	
Reverse Leakage	V _R = 10 Volts, T _{amb} = 75 °C	I _R	**	100	µA	
Junction Capacitance	f = 1MHz, V _R = 0 volt	C _J	0.8		pF	
Reverse Recovery Time	trr (If = 5 mA. Irr (rec.)@0.5 mA, Vr= -40 Volts)	trr	--	***	300	nSec
Forward Recovery Voltage	If = 50 mA PeakSine wave 100 KHz	Vfr	--	***	3.0	Volts

